NX3L1T384

Low-ohmic single-pole single-throw analog switch

Rev. 01 — 29 September 2009

Product data sheet

1. General description

The NX3L1T384 provides one single-pole single-throw analog switch function. It has two input/output terminals (Y and Z) and an active LOW enable input pin (\overline{E}) . When \overline{E} is HIGH, the analog switch is turned off.

Schmitt trigger action at the enable input (\overline{E}) makes the circuit tolerant to slower input rise and fall times across the entire V_{CC} range from 1.4 V to 4.3 V.

A low input voltage threshold allows pin \overline{E} to be driven by lower level logic signals without a significant increase in supply current I_{CC} . This makes it possible for the NX3L1T384 to switch 4.3 V signals with a 1.8 V digital controller, eliminating the need for logic level translation.

The NX3L1T384 allows signals with amplitude up to V_{CC} to be transmitted from Y to Z; or from Z to Y. Its low ON resistance (0.5 Ω) and flatness (0.13 Ω) ensures minimal attenuation and distortion of transmitted signals.

2. Features

- Wide supply voltage range from 1.4 V to 4.3 V
- Very low ON resistance (peak):
 - 1.6 Ω (typical) at $V_{CC} = 1.4 \text{ V}$
 - 1.0 Ω (typical) at $V_{CC} = 1.65 \text{ V}$
 - 0.55 Ω (typical) at V_{CC} = 2.3 V
 - 0.50 Ω (typical) at V_{CC} = 2.7 V
 - 0.50 Ω (typical) at V_{CC} = 4.3 V
- High noise immunity
- ESD protection:
 - HBM JESD22-A114F Class 3A exceeds 7500 V
 - ◆ MM JESD22-A115-A exceeds 200 V
 - ◆ CDM AEC-Q100-011 revision B exceeds 1000 V
- CMOS low-power consumption
- Latch-up performance exceeds 100 mA per JESD78B Class II Level A
- 1.8 V control logic at V_{CC} = 3.6 V
- Control input accepts voltages above supply voltage
- Very low supply current, even when input is below V_{CC}
- High current handling capability (350 mA continuous current under 3.3 V supply)
- Specified from -40 °C to +85 °C and from -40 °C to +125 °C



Low-ohmic single-pole single-throw analog switch

3. Applications

- Cell phone
- PDA
- Portable media player

4. Ordering information

Table 1. Ordering information

Type number	Package								
	Temperature range	Name	Description	Version					
NX3L1T384GW	–40 °C to +125 °C	TSSOP5	plastic thin shrink small outline package; 5 leads; body width 1.25 mm	SOT353-1					
NX3L1T384GM	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 \times 1.45 \times 0.5 mm	SOT886					

5. Marking

Table 2. Marking codes[1]

Type number	Marking code
NX3L1T384GW	M3
NX3L1T384GM	M3

^[1] The pin 1 indicator is located on the lower left corner of the device, below the marking code.

6. Functional diagram



Low-ohmic single-pole single-throw analog switch

7. Pinning information

7.1 Pinning



7.2 Pin description

Table 3. Pin description

Symbol	Pin		Description
	SOT353-1	SOT886	
Υ	1	1	independent input or output
Z	2	2	independent output or input
GND	3	3	ground (0 V)
Ē	4	4	enable input (active LOW)
n.c.	-	5	not connected
V _{CC}	5	6	supply voltage

8. Functional description

Table 4. Function table[1]

Input E	Switch
L	ON-state
Н	OFF-state

^[1] H = HIGH voltage level; L = LOW voltage level.

Low-ohmic single-pole single-throw analog switch

9. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		-0.5	+4.6	V
VI	input voltage	enable input E	[<u>1]</u> -0.5	+4.6	V
V _{SW}	switch voltage		[2] -0.5	$V_{CC} + 0.5$	V
I _{IK}	input clamping current	$V_1 < -0.5 \text{ V}$	-50	-	mΑ
I _{SK}	switch clamping current	$V_{I} < -0.5 \text{ V or } V_{I} > V_{CC} + 0.5 \text{ V}$	-	±50	mΑ
I _{SW}	switch current	$V_{SW} > -0.5 \text{ V or } V_{SW} < V_{CC} + 0.5 \text{ V};$ source or sink current	-	±350	mA
		V_{SW} > -0.5 V or V_{SW} < V_{CC} + 0.5 V; pulsed at 1 ms duration, < 10 % duty cycle; peak current	-	±500	mA
T _{stg}	storage temperature		-65	+150	°C
P _{tot}	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$	[3] _	250	mW

^[1] The minimum input voltage rating may be exceeded if the input current rating is observed.

10. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Max	Unit
V_{CC}	supply voltage		1.4	4.3	V
V_{I}	input voltage	enable input $\overline{\overline{E}}$	0	4.3	V
V_{SW}	switch voltage		<u>[1]</u> 0	V_{CC}	V
T_{amb}	ambient temperature		-40	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	$V_{CC} = 1.4 \text{ V to } 4.3 \text{ V}$	[2] _	200	ns/V

^[1] To avoid sinking GND current from of terminal Z when switch current flows in terminal Y, the voltage drop across the bidirectional switch must not exceed 0.4 V. If the switch current flows into terminal Z, no GND current will flow from terminal Y. In this case, there is no limit for the voltage drop across the switch.

^[2] The minimum and maximum switch voltage ratings may be exceeded if the switch clamping current rating is observed but may not exceed 4.6 V.

^[3] For TSSOP5 package: above 87.5 °C the value of P_{tot} derates linearly with 4.0 mW/K. For XSON6 package: above 118 °C the value of P_{tot} derates linearly with 7.8 mW/K.

^[2] Applies to control signal levels.

Low-ohmic single-pole single-throw analog switch

11. Static characteristics

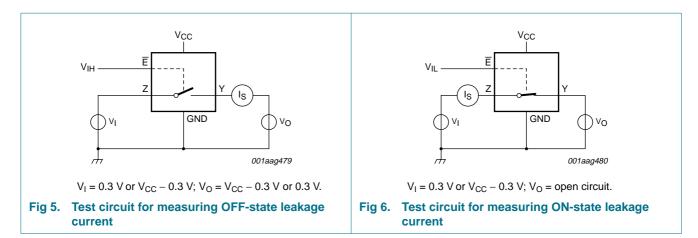
Table 7. Static characteristics

At recommended operating conditions; voltages are referenced to GND (ground 0 V).

Symbol	Parameter	Conditions		25 °C		-40	Unit		
			Min	Тур	Max	Min	Max (85 °C)	Max (125 °C)	
V_{IH}	HIGH-level	V _{CC} = 1.4 V to 1.6 V	0.9	-	-	0.9	-	-	V
	input voltage	V _{CC} = 1.65 V to 1.95 V	0.9	-	-	0.9	-	-	V
		V _{CC} = 2.3 V to 2.7 V	1.1	-	-	1.1	-	-	V
		V _{CC} = 2.7 V to 3.6 V	1.3	-	-	1.3	-	-	V
		V _{CC} = 3.6 V to 4.3 V	1.4	-	-	1.4	-	-	V
V_{IL}	LOW-level	V _{CC} = 1.4 V to 1.6 V	-	-	0.3	-	0.3	0.3	V
	input voltage	V _{CC} = 1.65 V to 1.95 V	-	-	0.4	-	0.4	0.3	V
		V _{CC} = 2.3 V to 2.7 V	-	-	0.4	-	0.4	0.4	V
		V _{CC} = 2.7 V to 3.6 V	-	-	0.5	-	0.5	0.5	V
		V _{CC} = 3.6 V to 4.3 V	-	-	0.6	-	0.6	0.6	V
I _I	input leakage current	enable input \overline{E} ; V _I = GND to 4.3 V; V _{CC} = 1.4 V to 4.3 V	-	-	-	-	±0.5	±1	μΑ
I _{S(OFF)} OFF-state		Y port; see Figure 5							
	leakage	$V_{CC} = 1.4 \text{ V to } 3.6 \text{ V}$	-	-	±5	-	±50	±500	nA
	current	$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	-	±10	-	±50	±500	nΑ
I _{S(ON)}	ON-state	Z port; see Figure 6							
	leakage	$V_{CC} = 1.4 \text{ V to } 3.6 \text{ V}$	-	-	±5	-	±50	±500	nΑ
	current	$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	-	±10	-	±50	±500	nΑ
I _{CC}	supply current	$V_I = V_{CC}$ or GND; $V_{SW} = GND$ or V_{CC}							
		V _{CC} = 3.6 V	-	-	100	-	690	6000	nΑ
		V _{CC} = 4.3 V	-	-	150	-	800	7000	nΑ
ΔI_{CC}	additional	$V_{SW} = GND \text{ or } V_{CC}$							
	supply current	$V_{I} = 2.6 \text{ V}; V_{CC} = 4.3 \text{ V}$	-	2.0	4.0	-	7	7	μΑ
		$V_{I} = 2.6 \text{ V}; V_{CC} = 3.6 \text{ V}$	-	0.35	0.7	-	1	1	μΑ
		$V_{I} = 1.8 \text{ V}; V_{CC} = 4.3 \text{ V}$	-	7.0	10.0	-	15	15	μΑ
		$V_I = 1.8 \text{ V}; V_{CC} = 3.6 \text{ V}$	-	2.5	4.0	-	5	5	μΑ
		$V_I = 1.8 \text{ V}; V_{CC} = 2.5 \text{ V}$	-	50	200	-	300	500	nΑ
Cı	input capacitance		-	1.0	-	-	-	-	pF
C _{S(OFF)}	OFF-state capacitance		-	35	-	-	-	-	pF
C _{S(ON)}	ON-state capacitance		-	110	-	-	-	-	pF

Low-ohmic single-pole single-throw analog switch

11.1 Test circuits



11.2 ON resistance

Table 8. ON resistance

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for graphs see Figure 8 to Figure 14.

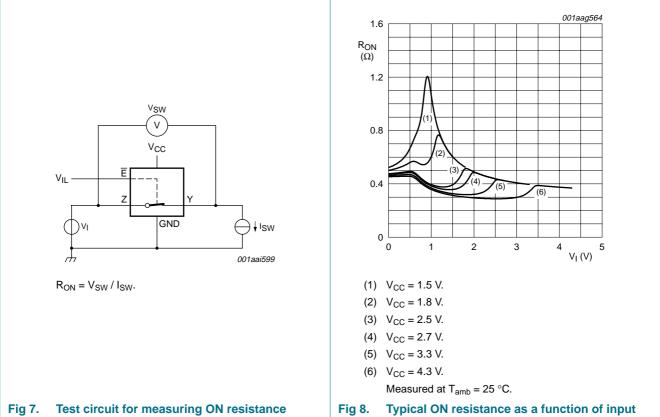
Symbol	Parameter	Conditions		T_{amb} = -40 °C to +85 °C			T _{amb} = -40 °	C to +125 °C	Unit
			N	lin	Typ[1]	Max	Min	Max	
R _{ON(peak)} ON resistance (peak)	ON resistance (peak)	$V_I = GND$ to V_{CC} ; $I_{SW} = 100$ mA; see Figure 7							
		V _{CC} = 1.4 V		-	1.6	3.7	-	4.1	Ω
		V _{CC} = 1.65 V		-	1.0	1.6	-	1.7	Ω
		V _{CC} = 2.3 V		-	0.55	8.0	-	0.9	Ω
		V _{CC} = 2.7 V		-	0.5	0.75	-	0.9	Ω
		$V_{CC} = 4.3 \text{ V}$		-	0.5	0.75	-	0.9	Ω
$R_{ON(flat)}$	ON resistance (flatness)	$V_I = GND \text{ to } V_{CC};$ $I_{SW} = 100 \text{ mA}$	[2]						
		$V_{CC} = 1.4 \text{ V}$		-	1.0	3.3	-	3.6	Ω
		V _{CC} = 1.65 V		-	0.5	1.2	-	1.3	Ω
		$V_{CC} = 2.3 \text{ V}$		-	0.15	0.3	-	0.35	Ω
		$V_{CC} = 2.7 \text{ V}$		-	0.13	0.3	-	0.35	Ω
		$V_{CC} = 4.3 \text{ V}$		-	0.2	0.4	-	0.45	Ω

^[1] Typical values are measured at T_{amb} = 25 °C.

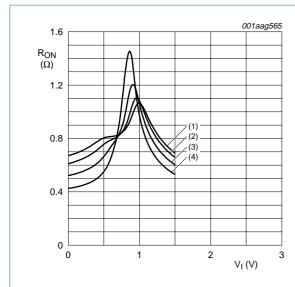
^[2] Flatness is defined as the difference between the maximum and minimum value of ON resistance measured at identical V_{CC} and temperature.

Low-ohmic single-pole single-throw analog switch

11.3 ON resistance test circuit and graphs

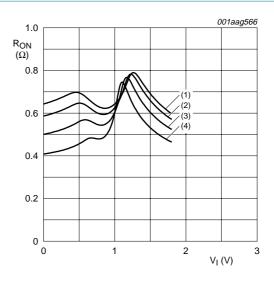


Low-ohmic single-pole single-throw analog switch



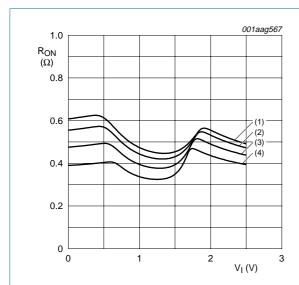
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 9. ON resistance as a function of input voltage; $V_{CC} = 1.5 \text{ V}$



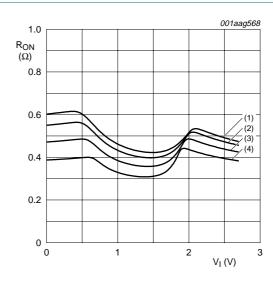
- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 10. ON resistance as a function of input voltage; $V_{CC} = 1.8 \text{ V}$



- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

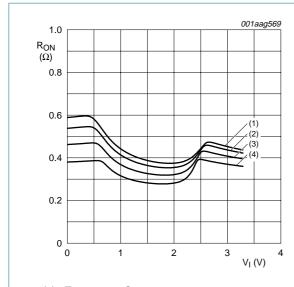
Fig 11. ON resistance as a function of input voltage; $V_{CC} = 2.5 \text{ V}$



- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

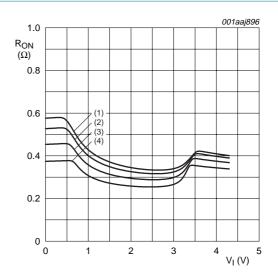
Fig 12. ON resistance as a function of input voltage; $V_{CC} = 2.7 \text{ V}$

Low-ohmic single-pole single-throw analog switch



- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 13. ON resistance as a function of input voltage; $V_{CC} = 3.3 \text{ V}$



- (1) $T_{amb} = 125 \, ^{\circ}C$.
- (2) $T_{amb} = 85 \, ^{\circ}C$.
- (3) $T_{amb} = 25 \, ^{\circ}C$.
- (4) $T_{amb} = -40 \, ^{\circ}C$.

Fig 14. ON resistance as a function of input voltage; $V_{CC} = 4.3 \text{ V}$

12. Dynamic characteristics

Table 9. Dynamic characteristics

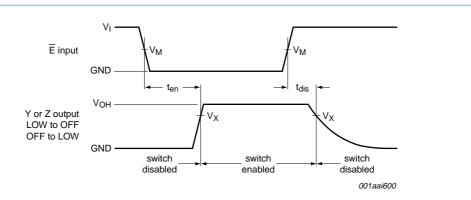
At recommended operating conditions; voltages are referenced to GND (ground = 0 V); for load circuit see Figure 16.

Symbol	Parameter	Conditions	25 °C			-40	Unit		
			Min	Typ[1]	Max	Min	Max (85 °C)	Max (125 °C)	
t _{en}	enable time	E to Z or Y; see Figure 15							
		V_{CC} = 1.4 V to 1.6 V	-	50	90	-	120	120	ns
		V_{CC} = 1.65 V to 1.95 V	-	36	70	-	80	90	ns
		V_{CC} = 2.3 V to 2.7 V	-	24	45	-	50	55	ns
		V_{CC} = 2.7 V to 3.6 V	-	22	40	-	45	50	ns
		V_{CC} = 3.6 V to 4.3 V	-	22	40	-	45	50	ns
t _{dis}	disable time	E to Z or Y; see Figure 15							
		V_{CC} = 1.4 V to 1.6 V	-	30	45	-	50	60	ns
		V_{CC} = 1.65 V to 1.95 V	-	20	30	-	35	40	ns
		V_{CC} = 2.3 V to 2.7 V	-	15	20	-	22	25	ns
		V_{CC} = 2.7 V to 3.6 V	-	11	15	-	18	22	ns
		$V_{CC} = 3.6 \text{ V to } 4.3 \text{ V}$	-	11	15	-	18	22	ns

^[1] Typical values are measured at $T_{amb} = 25$ °C and $V_{CC} = 1.5$ V, 1.8 V, 2.5 V, 3.3 V and 4.3 V respectively.

Low-ohmic single-pole single-throw analog switch

12.1 Waveform and test circuits



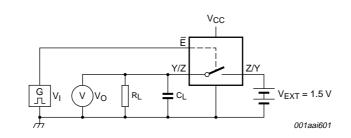
Measurement points are given in Table 10.

Logic level: V_{OH} is the typical output voltage that occurs with the output load.

Fig 15. Enable and disable times

Table 10. Measurement points

Supply voltage	Input	Output
V _{CC}	V _M	V _X
1.4 V to 4.3 V	0.5V _{CC}	0.9V _{OH}



Test data is given in Table 11.

Definitions test circuit:

R_L = Load resistance.

 C_L = Load capacitance including jig and probe capacitance.

 V_{EXT} = External voltage for measuring switching times.

Fig 16. Load circuit for switching times

Table 11. Test data

Supply voltage	Input		Load	
V _{CC}	VI	t _r , t _f	CL	R _L
1.4 V to 4.3 V	V_{CC}	≤ 2.5 ns	35 pF	50 Ω

Low-ohmic single-pole single-throw analog switch

12.2 Additional dynamic characteristics

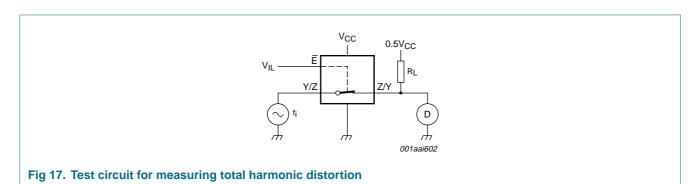
Table 12. Additional dynamic characteristics

At recommended operating conditions; voltages are referenced to GND (ground = 0 V); V_I = GND or V_{CC} (unless otherwise specified); t_r = $t_f \le 2.5$ ns.

Symbol	Parameter	Conditions	Conditions		T _{amb} = 25 °C		Unit
				Min	Тур	Max	
THD	total harmonic	f_i = 20 Hz to 20 kHz; R_L = 32 Ω ; see Figure 17	<u>[1]</u>				
	distortion	$V_{CC} = 1.4 \text{ V}; V_I = 1 \text{ V (p-p)}$		-	0.15	-	%
		V _{CC} = 1.65 V; V _I = 1.2 V (p-p)		-	0.10	-	%
		$V_{CC} = 2.3 \text{ V}; V_I = 1.5 \text{ V (p-p)}$		-	0.02	-	%
		$V_{CC} = 2.7 \text{ V}; V_I = 2 \text{ V (p-p)}$		-	0.02	-	%
		$V_{CC} = 4.3 \text{ V}; V_{I} = 2 \text{ V (p-p)}$		-	0.02	-	%
f _(-3dB)	-3 dB frequency	$R_L = 50 \Omega$; see Figure 18	<u>[1]</u>				
	response	V _{CC} = 1.4 V to 4.3 V		-	60	-	MHz
α_{iso}	isolation (OFF-state)	f_i = 100 kHz; R_L = 50 Ω ; see Figure 19	<u>[1]</u>				
		V _{CC} = 1.4 V to 4.3 V		-	-90	-	dB
V_{ct}	crosstalk voltage	between digital inputs and switch; $f_i = 1$ MHz; $C_L = 50$ pF; $R_L = 50$ Ω ; see Figure 20					
		V _{CC} = 1.4 V to 3.6 V		-	0.2	-	V
		V _{CC} = 3.6 V to 4.3 V		-	0.2	-	V
Q_{inj}	charge injection	f_i = 1 MHz; C_L = 0.1 nF; R_L = 1 M Ω ; V_{gen} = 0 V; R_{gen} = 0 Ω ; see Figure 21					
		V _{CC} = 1.5 V		-	3	-	рС
		V _{CC} = 1.8 V		-	3	-	рС
		V _{CC} = 2.5 V		-	3	-	рС
		V _{CC} = 3.3 V		-	3	-	рС
		V _{CC} = 4.3 V		-	6	-	рС

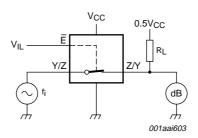
^[1] f_i is biased at 0.5 V_{CC} .

12.3 Test circuits



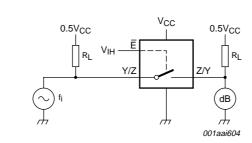
NX3L1T384_1 © NXP B.V. 2009. All rights reserved.

Low-ohmic single-pole single-throw analog switch



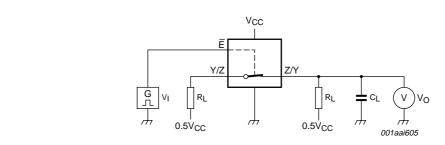
Adjust f_i voltage to obtain 0 dBm level at output. Increase f_i frequency until dB meter reads –3 dB.

Fig 18. Test circuit for measuring the frequency response when channel is in ON-state

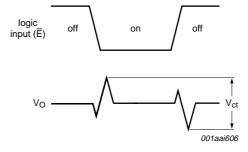


Adjust fi voltage to obtain 0 dBm level at input.

Fig 19. Test circuit for measuring isolation (OFF-state)



a. Test circuit

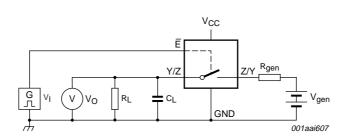


b. Input and output pulse definitions

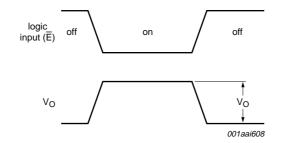
Fig 20. Test circuit for measuring crosstalk voltage between digital inputs and switch

NX3L1T384_1 © NXP B.V. 2009. All rights reserved.

Low-ohmic single-pole single-throw analog switch



a. Test circuit



b. Input and output pulse definitions

Definition: $Q_{inj} = \Delta V_O \times C_L$.

 ΔV_{O} = output voltage variation.

 R_{gen} = generator resistance. V_{gen} = generator voltage.

Fig 21. Test circuit for measuring charge injection

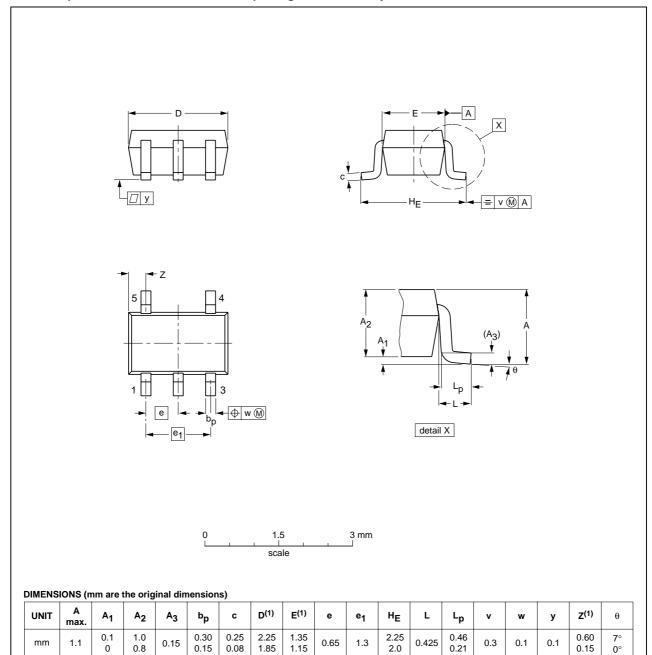
NX3L1T384

Low-ohmic single-pole single-throw analog switch

13. Package outline

TSSOP5: plastic thin shrink small outline package; 5 leads; body width 1.25 mm

SOT353-1



. .

1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.

OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT353-1		MO-203	SC-88A			00-09-01 03-02-19

Fig 22. Package outline SOT353-1 (TSSOP5)

NX3L1T384_1 © NXP B.V. 2009. All rights reserved.

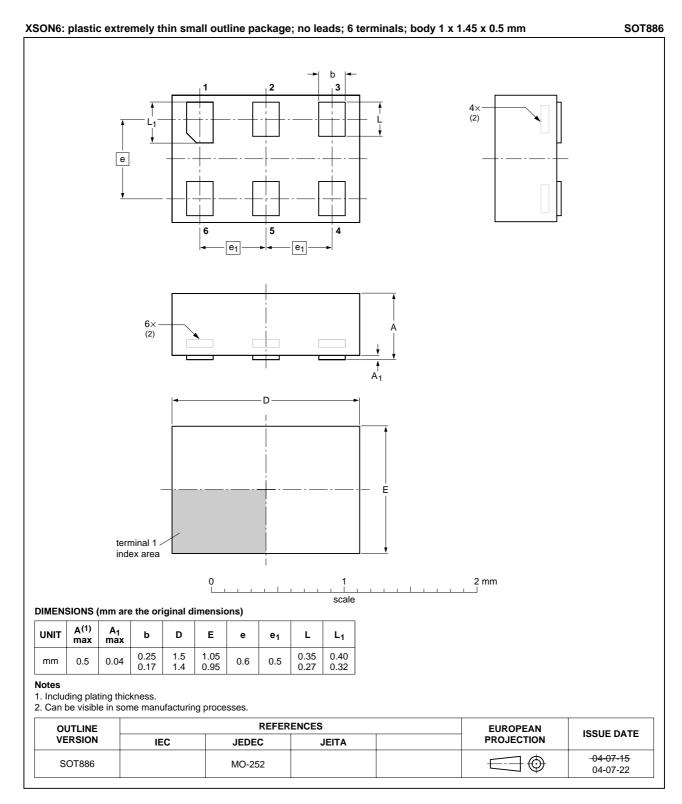


Fig 23. Package outline SOT886 (XSON6)

Low-ohmic single-pole single-throw analog switch

14. Abbreviations

Table 13. Abbreviations

Acronym	Description	
CDM	Charged-Device Model	
CMOS	Complementary Metal-Oxide Semiconductor	
ESD	ElectroStatic Discharge	
HBM	Human Body Model	
MM	Machine Model	
PDA	Personal Digital Assistant	

15. Revision history

Table 14. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
NX3L1T384_1	20090929	Product data sheet	-	-

Low-ohmic single-pole single-throw analog switch

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- [3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

16.2 Definitions

Draft — The document is a draft version only. The content is still under internal review and subject to formal approval, which may result in modifications or additions. NXP Semiconductors does not give any representations or warranties as to the accuracy or completeness of information included herein and shall have no liability for the consequences of use of such information.

Short data sheet — A short data sheet is an extract from a full data sheet with the same product type number(s) and title. A short data sheet is intended for quick reference only and should not be relied upon to contain detailed and full information. For detailed and full information see the relevant full data sheet, which is available on request via the local NXP Semiconductors sales office. In case of any inconsistency or conflict with the short data sheet, the full data sheet shall prevail.

16.3 Disclaimers

General — Information in this document is believed to be accurate and reliable. However, NXP Semiconductors does not give any representations or warranties, expressed or implied, as to the accuracy or completeness of such information and shall have no liability for the consequences of use of such information.

Right to make changes — NXP Semiconductors reserves the right to make changes to information published in this document, including without limitation specifications and product descriptions, at any time and without notice. This document supersedes and replaces all information supplied prior to the publication hereof.

Suitability for use — NXP Semiconductors products are not designed, authorized or warranted to be suitable for use in medical, military, aircraft, space or life support equipment, nor in applications where failure or malfunction of an NXP Semiconductors product can reasonably be expected to result in personal injury, death or severe property or environmental

damage. NXP Semiconductors accepts no liability for inclusion and/or use of NXP Semiconductors products in such equipment or applications and therefore such inclusion and/or use is at the customer's own risk.

Applications — Applications that are described herein for any of these products are for illustrative purposes only. NXP Semiconductors makes no representation or warranty that such applications will be suitable for the specified use without further testing or modification.

Limiting values — Stress above one or more limiting values (as defined in the Absolute Maximum Ratings System of IEC 60134) may cause permanent damage to the device. Limiting values are stress ratings only and operation of the device at these or any other conditions above those given in the Characteristics sections of this document is not implied. Exposure to limiting values for extended periods may affect device reliability.

Terms and conditions of sale — NXP Semiconductors products are sold subject to the general terms and conditions of commercial sale, as published at http://www.nxp.com/profile/terms, including those pertaining to warranty, intellectual property rights infringement and limitation of liability, unless explicitly otherwise agreed to in writing by NXP Semiconductors. In case of any inconsistency or conflict between information in this document and such terms and conditions, the latter will prevail.

No offer to sell or license — Nothing in this document may be interpreted or construed as an offer to sell products that is open for acceptance or the grant, conveyance or implication of any license under any copyrights, patents or other industrial or intellectual property rights.

Export control — This document as well as the item(s) described herein may be subject to export control regulations. Export might require a prior authorization from national authorities.

16.4 Trademarks

Notice: All referenced brands, product names, service names and trademarks are the property of their respective owners.

17. Contact information

For more information, please visit: http://www.nxp.com

For sales office addresses, please send an email to: salesaddresses@nxp.com

NXP Semiconductors

NX3L1T384

Low-ohmic single-pole single-throw analog switch

18. Contents

1	General description 1
2	Features
3	Applications
4	Ordering information 2
5	Marking 2
6	Functional diagram 2
7	Pinning information 3
7.1	Pinning
7.2	Pin description
8	Functional description 3
9	Limiting values 4
10	Recommended operating conditions 4
11	Static characteristics 5
11.1	Test circuits 6
11.2	ON resistance
11.3	ON resistance test circuit and graphs 7
12	Dynamic characteristics 9
12.1	Waveform and test circuits 10
12.2	Additional dynamic characteristics 11
12.3	Test circuits
13	Package outline
14	Abbreviations
15	Revision history
16	Legal information
16.1	Data sheet status
16.2	Definitions
16.3	Disclaimers
16.4	Trademarks17
17	Contact information
18	Contents

Please be aware that important notices concerning this document and the product(s) described herein, have been included in section 'Legal information'.

